


	<h2 style="color: red;">FQB12N60TM_AM002</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQB12N60TM_AM002</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 600V 10.5A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB12N60TM_AM002.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32363 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQB12N60TM_AM002</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 600V 10.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10.5A (Tc)
Rds On (Max) @ Id, Vgs	700 mOhm @ 5.3A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	54nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1900pF @ 25V
Verpackung	Tape & Reel (TR)














































FQB12N60TM\_AM002 ist neu im Original, Suche FQB12N60TM\_AM002 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB12N60TM\_AM002 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB12N60TM\_AM002: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB12P20</b> FSC FQB12P20 FSC	 <b>FQB12N60CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A D2PAK	 <b>FQB12N60CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 12A D2PAK	 <b>FQB12P10TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 11.5A D2PAK
 <b>FQB12N60TM</b> Fairchild/ON Semiconductor FQB12N60TM FAIRCHILD	 <b>FQB12P10</b> FSC FQB12P10 FSC	 <b>FQB12N60TM_AM002</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 10.5A D2PAK	 <b>FQB12N60C</b> Fairchild/ON Semiconductor FQB12N60C FAIRCHILD

### heiße Teile

Mehr

 FQB10N50CF	 FQB10N50CFTM	 FQB10N50CFTM_WS	 FQB10N60C	 FQB10N60CTM
 FQB10N60CTM	 FQB11N40	 FQB11N40C	 FQB11N40CTM	 FQB11N40CTM
 FQB11N60FTM	 FQB11N60TM	 FQB11P06	 FQB11P06TM	 FQB11P06TM
 FQB11P06TM**CN-SCI	 FQB12N50TM	 FQB12N50TM_AM002	 FQB12N50TM_AM002	 FQB12N60
 FQB12N60C	 FQB12N60CTM	 FQB12N60CTM	 FQB12N60TM	 FQB12N60TM_AM002
 FQB12P10	 FQB12P10TM	 FQB12P10TM	 FQB12P20	 FQB12P20TM
 FQB12P20TM	 FQB13N06L	 FQB13N10	 FQB13N10L	 FQB13N50
 FQB13N50CTM	 FQB13N50CTM	 FQB140N03L	 FQB14N30TM	 FQB14N30TM
 FQB16N25TM	 FQB16N25TM	 FQB17P06	 FQB17P10	 FQB17P10TM
 FQB17P10TM	 FQB19N10L	 FQB19N10LTM	 FQB19N10LTM	 FQB19N10TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited